

2D bands and electron-phonon interactions in polyacene plastic transistors

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 (February 1, 2008)

We present a simple tight-binding model for the two-dimensional energy bands of polyacene field-effect transistors and for the coupling of these bands to lattice vibrations of their host molecular crystal. We argue that the strongest electron-phonon interactions in these systems originate from the dependence of inter-molecule hopping amplitudes on collective molecular motion, and introduce a generalized Su-Schrieffer-Heeger model that accounts for all vibrations and is parameter-free once the band mass has been specified. We compute the electron-phonon spectral function $\alpha^2 F(\omega)$ as a function of two-dimensional hole density, and are able to explain the onset of superconductivity near 2D carrier density $n_{2D} \sim 10^{14} \text{cm}^{-2}$, discovered in recent experiments by Schön *et al.* [1].

63.20.-e, 63.20.Kr, 73.40.-c, 74.55.+h

Recent studies [1,2] of high-mobility organic field-effect transistors by Battlogg and collaborators have demonstrated that their electronic properties can be tuned through an astonishing range, simply by adjusting the two-dimensional (2D) electron density n_{2D} with a gate voltage. The high quality of these organic single crystals and of their interfaces with AlO_3 dielectrics opens up new possibilities for studying the physics of coherent *band* quasiparticle transport in organic semiconductors. To date, however, the analysis of organic field-effect-transistor electronic systems has been hampered by the absence of simple and reliable models for their electronic quasiparticles and for the interactions of these quasiparticles with each other and with vibrations of the host lattice. Indeed the discovery of coherent band quasiparticle properties and of the quantum Hall effect in these systems, which are usually thought of as being complex and relatively disordered, has been one of the major surprises that has emerged from recent materials quality advances.

The electronic properties of polyacene semiconductors are normally described by *small polaron* theory [3], which is quite successful at temperatures above ≈ 20 K. Small polaron theory starts from localized molecular orbitals and is therefore unable to describe the low-temperature *band* quasiparticle behavior seen in Battlogg *et al.*'s samples, which have room-temperature to low temperature resistance ratios $\sim 10^4$. Schubnikov-de Haas transport studies in these samples establish quasiparticle mean-free-paths in excess of 1000 lattice constants, demonstrating that the low-temperature regime can be described only by starting at the opposite limit and building a theory based on delocalized band electron states. Nevertheless, the interactions of quasiparticles with lattice vibrations remain strong, and are presumably responsible for superconductivity. In this Letter, we propose a simple tight-binding model for the quasiparticle bands that emerge from π -molecular orbitals and are filled with carriers by the field-effect, and for the interaction of these

bands with the host crystal vibrational excitations. Our theory is parameter free once the band mass has been specified [2].

We find that over the entire wide range of studied densities, the quasiparticles of these systems lie within a single 2D band, bound to the crystal surface by the transistor's electric field. We argue that the dominant electron-phonon interactions in polyacene crystals differ qualitatively from the deformation and Frohlich interactions of inorganic semiconductors [4] and from the intra-molecule interactions that dominate in doped fullerenes [5], being more similar instead to those of doped polyacetylene [6] crystals. We describe these interactions using a Su-Schrieffer-Heeger model [6], detailed in the following paragraphs, generalized to account for the larger number of important rigid molecule motions. The lattice phonons, a mixture in general of translational and librational components, induce a change in the value of the hopping integral and hence couple [6] to the quasiparticle bands. We estimate the variation of hopping parameters with vibrational normal coordinates by assuming that they are proportional to the spatial overlap of Hückel-type LUMO and HOMO molecular orbitals, with the proportionality constant fixed by matching the measured equilibrium hopping parameter [7]. In this way, we have evaluated the carrier density dependence of $\alpha^2 F(\omega)$, the index of electron-phonon interactions that figures prominently in the theory of phonon-mediated superconductivity. We find peaks that match the spectrum extracted from recent tunneling experiments [2]. We also find that $\alpha^2 F(\omega)$ is large, due to a density-of-states peak, when the lowest energy 2D subband is close to half-filling. We propose this property as the explanation of the relatively sharp onset of superconductivity at a 2D carrier density of $\approx 10^{14} \text{cm}^{-2}$ seen in experiments [1].

We focus in this study on anthracene which is monoclinic ($P2_1/a$) with two basis molecules whose orientations are related by a gliding plane symmetry [8]. Since

Huckel model intra-molecular hopping parameters have no linear dependence on low energy intra-molecular vibration normal coordinates, our model Hamiltonian includes only inter-molecular hopping parameters [9].

$$\mathcal{H} = \mathcal{H}_t + \mathcal{H}_{e-e} + \mathcal{H}_{\text{vib}} + \mathcal{H}_{\text{ext}}$$

where $\mathcal{H}_t$ is the LUMO or HOMO band Hamiltonian described by a nearest-neighbour hopping model, $\mathcal{H}_{e-e}$ describes Coulomb interaction between the electrons, $\mathcal{H}_{\text{vib}}$ is the free-phonon Hamiltonian, and $\mathcal{H}_{\text{ext}}$ describes the external electric field from the transistor's gate.

We start by considering the field-induced energy bands obtained neglecting electron-phonon interactions. The key question we need to address is the number of 2D subbands that are occupied at a particular 2D density, n_{2D} . As summarized in Fig. 1, we find that all carriers reside in a single subband up to much higher density in these transistors than in their inorganic counterparts, principally because of the relatively small dielectric constants ($\epsilon \sim 3.5$) and the large effective in plane band mass ($m_{\perp} = 1.5m_e$) and in spite of the rather large c-direction effective band mass $m_z \sim 3m_e$ [1,10]. Since the Al_2O_3 barrier is quite high ($\approx 1.3\text{eV}$), we take it to be infinite. Our conclusion is based partially on envelope-function density-functional calculations for which the local-density-approximation (LDA) can be used to estimate many-body effects [11,12] that favor a single subband. In our LDA calculations we find that the second subband is first populated at $n_{2D} \approx 5 - 7 \times 10^{14}\text{cm}^{-2}$, a density just larger than the highest achieved in experimental systems. However, as shown in the inset of Fig. 1, the wavefunctions in these calculations are already localized over $\sim 1 - 2\text{ nm}$ at densities well below this maximum value. We have therefore repeated these electronic structure calculations using our tight-binding model, and treating interactions in a Hartree approximation. With this approach we find that 99% of the charge density is in the first molecular layer at $n_{2D} = 3 \times 10^{13}\text{cm}^{-2}$, the density at which second subband occupation first occurs in this approximation. Since we believe that the experimental signatures of second subband occupation would be unambiguous and no anomalies in 2D density dependence have been reported, we conclude that a single 2D subband is occupied up to the highest densities and that the lowest subband is strongly localized in the top layer for n_{2D} larger than $\approx 10^{13}\text{cm}^{-2}$.

To model the electron-phonon interaction, we expand each $a - b$ plane hopping parameter to first order in the twelve coordinates that describe rigid rotations and displacements of neighboring polyacene molecules:

$$t = t_0 + \sum_{m=1}^6 \sum_{\mu} \tilde{t}_{\mu,m} \tilde{u}_{\mu,m} \quad (1)$$

where $\tilde{u}_{\mu,m}$ is the generalized displacement coordinate, $\mu = 1, 2$ is the molecular basis index, $m = 1, 2, 3$ de-

note displacements of the molecular center of mass along $\hat{x}, \hat{y}$ and $\hat{z}$ directions, and $m = 4, 5, 6$ denote angular displacements around the 1, 2, 3 principal axes of each molecule. The electron-phonon interaction parameters $\tilde{t}_{\mu,m} \equiv \partial t / \partial \tilde{u}_{\mu,m}$ are calculated based on the assumption of proportionality between hopping integrals and overlap integrals between HOMO or LUMO orbitals on adjacent molecules. The values obtained using standard Hückel approximation [7] HOMO π orbitals (and hence appropriate to the hole systems on which we focus) are listed in Table I in units of t_0/a for $m = 1, 2, 3$ and t_0 for $m = 4, 5, 6$.

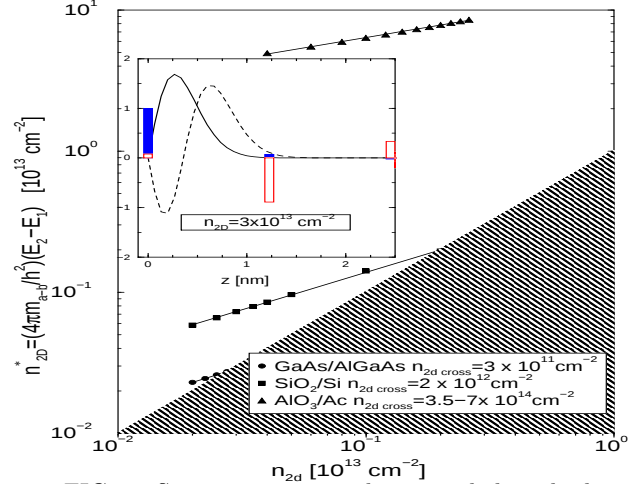


FIG. 1. States per area with energy below the bottom of the second subband *vs.* 2D electron density for GaAs, Si, and polyacene field effect transistors from envelope-function LDA calculations. Second subband occupation occurs in the hatched area. The inset shows first and second subband wavefunctions obtained from envelope function LDA and tight-binding model Hartree-approximation calculations (bars) at $n_{2D} = 3 \times 10^{13}\text{cm}^{-2}$.

We now derive expressions for the interactions between phonons of the host crystal and the 2D band quasiparticles whose Hamiltonian is:

$$\mathcal{H}_{2D}^0 = \sum_{\alpha \mathbf{k} \in \text{BZ}_{2D}} \sum_{i=1,2} (\epsilon_{i,\alpha}(\mathbf{k}) + E_{\alpha} - \mu) \hat{c}_{i,\mathbf{k}}^{\dagger} \hat{c}_{i,\mathbf{k}} \quad (2)$$

with

$$\epsilon_i(\mathbf{k}) = (-1)^i 2t_0 \left[\cos\left(\frac{k_x a + k_y b}{2}\right) + \cos\left(\frac{k_x a - k_y b}{2}\right) \right] \quad (3)$$

where E_{α} is obtained from the discrete layer subband calculation, the two electronic band indices originate from the two molecules per unit cell, and BZ_{2D} indicates the two dimensional rectangular lattice Brillouin zone. The generalized displacements $\tilde{u}_{\mu,m}$ in Eq. 1 can be written in terms of quantized vibrational normal modes as follows:

$$\tilde{u}_{\mu,m}(\mathbf{R}) = \sum_{\mathbf{Q} \in \text{BZ}, \nu} \sqrt{\frac{\hbar}{2M_{\mu,m} N \omega_{\nu}(\mathbf{Q})}} \times \left[\epsilon_{\mu,m}(\mathbf{Q}, \nu) \hat{a}_{\mathbf{Q},\nu} e^{i\mathbf{Q} \cdot \mathbf{R}} + \epsilon_{\mu,m}^*(\mathbf{Q}, \nu) \hat{a}_{-\mathbf{Q},\nu}^{\dagger} e^{-i\mathbf{Q} \cdot \mathbf{R}} \right]$$

Here N is the total number of unit cells, $\tilde{M}_{\mu m}$ is the molecular mass of the μ th molecule for $m = 1, 2, 3$ and the molecular moment of inertia around the $(m-3)$ 'th principal axis $I_{(m-3)}^\mu$ for $m=4,5,6$. The phonon frequencies and polarization vectors are obtained by solving the standard secular equation

$$\omega_i^2(\mathbf{q})\epsilon_m^i(\mathbf{q}, \mu) = \sum_{\nu, n} D_{\mu m, \nu n}(\mathbf{q})\epsilon_n^i(\mathbf{q}, \nu) \quad (4)$$

These eigenmodes are in general a mixture of displacements and rotations [13]. We compute the dynamical matrix following the procedure outlined in Ref. [14]. The phonon density-of-states and dispersion curves that emerge from these calculations are shown in Fig. 2. The rigid-molecule vibration restriction used here is a convenient but inessential approximation that can be complemented if necessary by including coupling to important isolated molecule vibrations; it is however reasonably accurate for low-frequency vibrations of anthracene becoming less reliable for larger polyacenes.

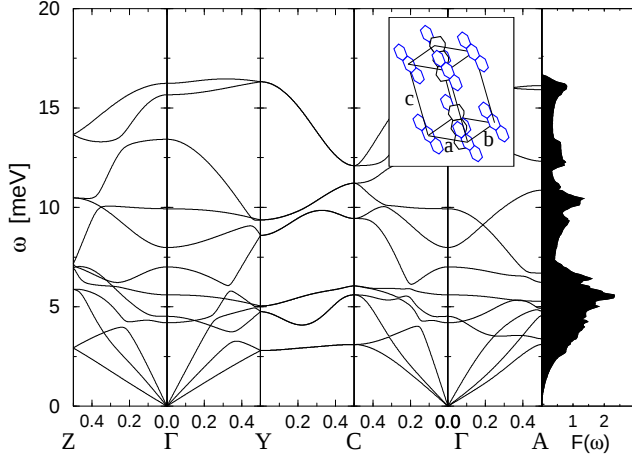


FIG. 2. Calculated dispersion curves in anthracene (structure shown in inset). Shown on the right is the phonon density of states $F(\omega)$ in units of meV^{-1} and normalized to 12, the number of vibrational modes considered.

Combining these ingredients we finally rewrite the Hamiltonian (treating Coulomb interactions at the mean field level) as

$$\mathcal{H} = \mathcal{H}_{2D}^0 + \mathcal{H}_{2D\text{e-vib}} + \mathcal{H}_{\text{vib}} \quad (5)$$

where

$$\mathcal{H}_{2D\text{e-vib}} = \frac{1}{\sqrt{N}} \sum_{\mathbf{k} \in \text{BZ}} \sum_{\nu, \alpha, \beta, i, j} \sum_{\mathbf{Q} \in \text{BZ}} g_{i, \alpha; j, \beta}(\mathbf{k}, \mathbf{Q}, \nu) \times [\hat{a}_{\mathbf{Q}, \nu} + \hat{a}_{-\mathbf{Q}, \nu}^\dagger] \hat{c}_{i, \alpha[\mathbf{k}+\mathbf{Q}]}^\dagger \hat{c}_{j, \beta \mathbf{k}} \quad (6)$$

and

$$g_{i, \alpha; j, \beta}(\mathbf{k}, \mathbf{q}, q_z, \nu) = (-1)^i \frac{\tilde{f}_{\alpha, \beta}(q_z)}{2} \sum_{\tilde{\delta}', \mu, m} \sqrt{\frac{\hbar}{2\tilde{M}_{\mu, m}\omega_\nu(\mathbf{Q})}} \times \tilde{\mathbf{t}}_{\mu m}(\tilde{\delta}') \epsilon_{\mu m}(\mathbf{Q}, \nu) e^{i\mathbf{q} \cdot \tilde{\delta}'_\mu} (e^{-i\tilde{\delta}' \cdot [\mathbf{k}+\mathbf{q}]} + (-1)^{(i-j)} e^{i\tilde{\delta}' \cdot \mathbf{k}}). \quad (7)$$

In Eq. 7 $\tilde{f}_{\alpha, \beta}(q_z) = \sum_{z_l} a_l^{\alpha*} a_l^\beta e^{iq_z z_l}$ is the form factor of the subband tight-binding wavefunction and the brackets indicate reduction to the 2D BZ. In our calculations we use the strict 2D limit ($\tilde{f}_{\alpha, \alpha}(q_z) = 1$) because of the strong quantum confinement found in LDA and Hartree calculations.

We define the electron-phonon interaction spectral function in the standard way:

$$\alpha^2 F(\omega) \equiv \frac{1}{N g(\mu)} \sum_{\mathbf{k}, \mathbf{k}', i} \sum_{q_z, \nu} |g_{i, 1; i, 1}(\mathbf{k}, [\mathbf{k}' - \mathbf{k}], q_z, \nu)|^2 \times \delta(\epsilon_i(\mathbf{k}) - \mu) \delta(\epsilon_i(\mathbf{k}') - \mu) \delta(\omega - \omega_\nu([\mathbf{k}' - \mathbf{k}], q_z)) \quad (8)$$

where $g(\mu) = \sum_{\mathbf{k}} \delta(\epsilon_i(\mathbf{k}) - \mu)$ is the electronic density of states, and $[\mathbf{k}' - \mathbf{k}]$ denotes the projection of the $\mathbf{Q} = (\mathbf{k}' - \mathbf{k}, q_z)$ vector into the three dimensional BZ. The results of these calculations for densities $n_{2d} = 4.0 \times 10^{14} \text{ cm}^{-2}$, $n_{2D} = 1.4 \times 10^{14} \text{ cm}^{-2}$, and $n_{2D} = 6.7 \times 10^{13} \text{ cm}^{-2}$ are shown in Fig. 3. The peak locations in the low-frequency rigid molecule vibration regime agree with those observed in infrared absorption and tunneling data in pentacene crystals [2]. The mass enhancement factor λ , obtained from the integration of $2F\alpha^2(\omega)/\omega$, close to half filling is 0.25. Its sharp decay away from half filling (driven by the density of states) helps explain the sharp superconductivity onset observed in the experiments. We estimate the superconducting critical temperature by the [dimension independent] BCS expression $k_B T_c \approx \hbar \omega_D \exp[-1/\lambda]$. Such expression, using $\hbar \omega_D/k_B \approx 150 \text{ K}$ from Ref. [2], yields $\sim 3 \text{ K}$ in agreement with the experiments [1]. We note that the inclusion of the second-nearest-neighbour hopping tends to push the density of states peak to higher energies (densities). Adding a finite life time of the quasiparticles, will broaden these peaks, hence creating a plateau in the n_{2D} -dependence of T_c shifted to the right of half filling as observed in the experiments [1]. This last effect would lower also the T_c calculated at $n = 4.00 \times 10^{-12} \text{ cm}^{-2}$, worsening experimental agreement. However, given that E_F does not satisfy $E_F \gg \hbar \omega_{max}$, such estimates of T_c from λ are qualitative.

In summary we have presented a theory of the low-temperature quasiparticle bands in polyacene field effect transistors, and of the coupling of these bands to the host molecular crystal phonons. We predict that the quasiparticles lie in a single 2D tight-binding band up to the highest densities that have been achieved experimentally at present and that the most important electron-phonon interactions arise from the influence of approximately rigid molecular translations and rotations on hopping between HOMO and LUMO orbitals on adjacent molecules.

This picture implies a dependence of superconducting critical temperature on molecular lattice constant which contrasts with the case of doped fullerene superconductors. For the fullerenes, the important electron-phonon interactions are intramolecular so that T_c depends on intermolecular hopping only through the density-of-states. Decreasing the lattice constant, increases hopping, and hence decreases the density-of-states and T_c [5]. Here decreasing the lattice constant will also strengthen the important electron-phonon interactions. According to our theory, the latter effect dominates and T_c will increase with decreasing lattice constant. We find that phonon-mediated electron-electron interactions in polyacene molecular crystals are strong only when the 2D tight-binding band is close to half-filling and its density of states is relatively large. This occurs for 2D densities comparable to $4 \times 10^{14} \text{ cm}^{-2}$, where superconductivity turns on relatively abruptly. At lower carrier densities, $\lambda \ll 1$ and electron-electron interactions are dominated by repulsive Coulomb interactions, consistent with the occurrence of the fractional quantum Hall effect.

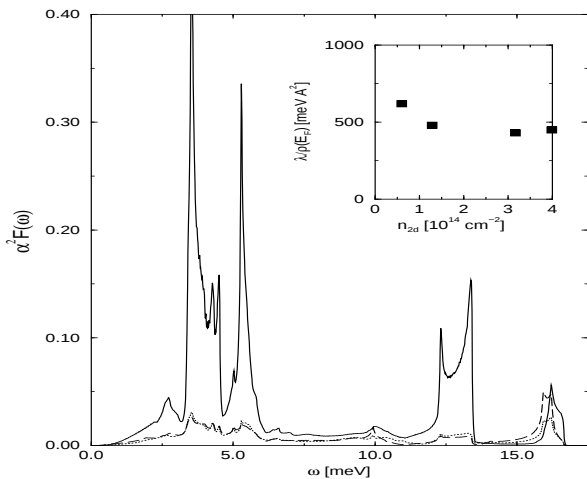


FIG. 3. $\alpha^2 F(\omega)$ for $n_{2d} = 4.0 \times 10^{14} \text{ cm}^{-2}$ (solid line), $n_{2d} = 1.4 \times 10^{14} \text{ cm}^{-2}$ (dotted line), and $n_{2d} = 6.7 \times 10^{13} \text{ cm}^{-2}$ (dashed line).

The authors acknowledge helpful discussions with P. Barbara, B. Batlogg, A. Dodabalapur, Y. Joglekar, T. Jungwirth, and P. Rossky. This work was supported by the Deutsche Forschungsgemeinschaft, by the Welch Foundation and the by the National Science Foundation under grant DMR0115947.

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- [7] Orbitals obtained through the Huckle approximation are in good agreement with the ones obtained through more sophisticated LDA calculations. See for example Ref. [5].
- [8] Here the crystal parameters are $a = 8.378 \text{ \AA}$, $b = 5.981 \text{ \AA}$, $c = 11.059 \text{ \AA}$, and $\beta = 125.34^\circ$ are the parameters at 4.7 K obtained from Dorner *et al* [13].
- [9] Higher frequency breathing modes of the isolated molecule will result in shifts of LUMO and HOMO levels, and to electron-phonon interactions that are not included in our model. However, these coupling are expected to be substantially screened in a molecular crystal and there is no evidence for their presence in tunneling studies of the polyacene superconducting state. For a discussion of this contribution see A. Devos and M. Lannoo, Phys. Rev. B **58**, 8236 (1998).
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$\delta_1 = (a/2, b/2)$	$\delta_1 = (a/2, b/2)$	$\delta_2 = (-a/2, -b/2)$
$t_{11} = 2.2706$	$t_{14} = 1.4895$	$t_{14} = -1.6095$
$t_{12} = 3.3842$	$t_{15} = 2.0318$	$t_{15} = 1.8288$
$t_{13} = 7.5308$	$t_{16} = 1.0082$	$t_{16} = 1.4658$

TABLE I. Electron-phonon interaction parameters. Note that interaction parameters for different near neighbors are different. All interaction parameters are related by symmetry to the nine values list above. A complete list of hopping parameters for all near neighbors of the two molecules in the crystal's primitive cell is available from the authors.

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